

ADA4177-2ARMZ

Data Sheet

perational Amplifier, 2	2 Amplifier, 3.5 MHz, 1.5 V/ μ s, \pm 5V to \pm 15V, MSOP, 8 Pins		
Manufacturers	Analog Devices, Inc		
Package/Case	MSOP8		
Product Type	Amplifier ICs	Sta	
RoHS	Pb-free Halide free		
Lifecycle		Images are for reference only	
Please submit RFQ for ADA4177-2ARMZ or Email to us: sales@ovaga.com We will contact you in 12 hours.			

General Description

The ADA4177-1 single-channel, ADA4177-2 dual-channel, and ADA4177-4 quad-channel amplifiers feature low offset voltage (2 μ V typical) and drift (1 μ V/°C maximum), low input bias current, low noise, and low current consumption (500 μ A typical). Outputs are stable with capacitive loads of more than 1000 pF with no external compensation.

The inputs of the ADA4177-1/ADA4177-2/ADA4177-4 feature outstanding precision amplifier robustness, providing input protection against signal excursions 32 V beyond either supply, as well as 70 dB of rejection for electromagnetic interference (EMI) at 1000 MHz.

Applications for these amplifiers include sensor signal conditioning (such as thermocouples, resistor thermal detectors (RTDs), and strain gages), process control front-end amplifiers, and precision diode power measurement in optical and wireless transmission systems.

The ADA4177-1/ADA4177-2/ADA4177-4 operate over the -40°C to +125°C industrial temperature range. The ADA4177-1/ADA4177-2 are available in an 8-lead SOIC package and an 8-lead MSOP package. The ADA4177-4 is available in a 14-lead TSSOP and a 14-lead SOIC package.

Features

Application

Low offset voltage: 60 μV maximum at 25°C (8-lead and 14-lead SOIC)	Wireless base station control circuits
Low offset voltage drift: 1 μ V/°C maximum (8-lead and 14-lead SOIC)	Optical network control circuits
Low input bias current: 1 nA maximum at 25°C	Instrumentation
Low voltage noise density: 8 nV/ \sqrt{Hz} typical at 1 kHz	Sensors and controls
Large signal voltage gain (AVO): 100 dB minimum over full supply voltage and operating temperature	, Thermocouples, RTDs, strain gages, shunt current measurements
Input overvoltage protection to 32 V above and below the supply voltage rail	
Integrated EMI filter	
70 dB typical rejection at 1000 MHz	
90 dB typical rejection at 2400 MHz	
Rail-to-rail output swing	
Low supply current: 500 µA typical per amplifier	
Wide bandwidth	
Gain bandwidth product>	
Unity-gain crossover>	
Dual-supply operation	
Specified at ± 5 V to ± 15 V, operates over ± 2.5 V to ± 18 V	
Unity-gain stable	
No phase reversal	
Long-term offset voltage drift (10,000 hours): 2 μ V typical	
Temperature hysteresis: 2 μ V typical	

Related Products



AD8418BRMZ-RL Analog Devices, Inc

MSOP-8



ADA4528-2ARMZ-R7

Analog Devices, Inc MSOP-8



ADA4084-2ARMZ

Analog Devices, Inc MSOP-8



AD8062ARMZ

Analog Devices, Inc MSOP8



AD8567ARUZ Analog Devices, Inc TSSOP-14

AD8022ARMZ Analog Devices, Inc MSOP-8



AD8628AUJZ

Analog Devices, Inc SOP23



<u>AD8041AR</u>

Analog Devices, Inc SOP-8